Highly Confined Hybrid Spoof Surface Plasmons in Ultrathin Metal-Dielectric Heterostructures

S. Hossein Mousavi,¹ Alexander B. Khanikaev,¹ Burton Neuner III,¹ Yoav Avitzour,¹ Dmitriy Korobkin,¹ Gabriel Ferro,² and Gennady Shvets^{1,*}

¹Department of Physics, University of Texas at Austin, Austin, Texas 78712, USA

²Laboratoire des Multimatériaux et Interfaces, Université Claude Bernard Lyon 1, 69622 Villeurbanne, France (Received 22 June 2010; revised manuscript received 27 August 2010; published 19 October 2010)

(Received 22 Julie 2010, Tevised manuscript Teceived 27 August 2010, published 19 October 2010)

Highly confined "spoof" surface plasmons (SSPs) are theoretically predicted to exist in a perforated metal film coated with a thin dielectric layer. Strong modes confinement results from the additional waveguiding by the layer. Spectral characteristics, field distribution, and lifetime of these SSPs are tunable by the holes' size and shape. SSPs exist both above and below the light line, offering two classes of applications: "perfect" far-field absorption and efficient emission into guided modes. It is experimentally shown that these plasmonlike modes can turn thin, weakly absorbing semiconductor films into perfect absorbers.

DOI: 10.1103/PhysRevLett.105.176803

PACS numbers: 73.20.Mf, 42.25.Bs, 42.79.Dj, 78.20.Ci

Introduction.-The surface plasmon (SP) is one of the linchpins of the field of subdiffraction optics [1]: by penetrating below the metal surface [2], electromagnetic waves can be localized beyond diffraction limit. This opens a wide range of applications in spectroscopy, photonic circuits, solar cells, and other technologically important areas [3–5]. For longer wavelengths, metals begin resembling perfect electric conductors (PECs), wave penetration into the metal becomes negligible, and other approaches to light localization and concentration must be found. It has been recently discovered [6–10] that SPs can be mimicked by perforating the metal surface with an array of subwavelength holes. Dispersion and confinement of the resulting "spoof" surface plasmons (SSPs) are defined (and can be tuned) by the holes' size and geometry. Thus, the SSPbased approach to light confinement is crucial for bringing the advantages of plasmonics into the longer-wavelength spectral range, which is especially important for various infrared applications, including surface-enhanced infrared absorption (SEIRA) spectroscopy [11,12], on-chip light sources [13], and infrared detectors [14,15].

A major drawback of SSPs supported by metal films with simple perforation geometries (e.g., circular or rectangular holes) is that they are very weakly confined for most frequencies and, therefore, are not suitable for the above applications. More sophisticated geometries that have been shown [10,16] to improve confinement in the microwave spectral range are not practical for optical applications. In this Letter, we resolve the problem of poor confinement of conventional SSPs while retaining their important advantage: the ability to control the SSP's frequency and refractive index using variable size and shape of the metal holes. This is achieved by combining metal structuring with the traditional method of electromagnetic field confinement, waveguiding. We theoretically predict and experimentally confirm that a new class of SSPs exists in the ultrathin heterostructure comprised of a slab of highindex dielectric material and a perforated metal film (Fig. 1). The resulting SSPs owe their unusual electromagnetic properties to their hybrid nature. The conventional SSP modes inherent to any periodic metal structure are hybridized with conventional modes of dielectric films: guided waves (GWs) and leaky Fabry-Pérot (FP) modes. The hybrid SSPs represent an important improvement on both conventional guided modes and SSPs: they are better confined than either one of the two (Fig. 3), while their spectral properties and lifetimes are controllable by the size and shape of the metallic perforations. As a specific example and possible application of the proposed concept, we demonstrate that hybrid SSPs can turn low-absorbing semiconductor (specifically, SiC) films into near-perfect absorbers of infrared radiation. The choice of SiC owes to the strong dependence of its dielectric permittivity $\epsilon_{\rm SiC}(\omega) \equiv$ $n^2(\omega)$ on frequency $\omega \equiv 2\pi c/\lambda$: $\epsilon_{\rm SiC}$ changes by a factor 2 as λ changes by 8% [17].

Theoretical description.—It is instructive to start the theoretical description of hybrid SSPs by considering the eigenmodes (both leaky and fully confined) of the *unperforated* heterostructure. Mathematically, this is done



FIG. 1 (color online). (Left) Schematic of the heterostructure supporting hybrid SSPs. (Right) Side view and definitions of the reflection and transmission coefficients used in the text.

by recalling the standard Airy expression [18] for the reflectivity coefficient of the heterostructure r_{slab} :

$$r_{\text{slab}} = r_{12} + t_{12}t_{21}\exp(2i\delta)r_{23}Z, \qquad \delta = k_z d, \quad (1)$$

where the reflection (transmission) coefficients $r_{ij} \equiv |r_{ij}|e^{i\phi_{ij}}(t_{ij})$ at the *i*th-*j*th medium interface are illustrated by Fig. 1, $Z \equiv 1/(1 - r_{21}r_{23}e^{2i\delta})$ accounts for multiple reflections, and k_z is the propagation wave number normal to the interface. All eigenmodes of the unperforated heterostructure (including leaky and fully guided modes) correspond to the poles of r_{slab} . These poles are given by $Z^{-1} = 0$, giving rise to the following condition that must be satisfied by any eigenmode:

$$\phi_{21} + \phi_{23} + 2\operatorname{Re}\{k_z\}d = 2\pi l, \qquad (2)$$

where *l* is an integer number. Note that $\phi_{23} = \pi$ in the case of unperforated PEC film, and the phase ϕ_{21} of the Fresnel's reflection coefficient satisfies $\phi_{21} = 0$ above the light line, but can depart from zero below the light line. The frequencies of the two eigenmodes found for real wave numbers along the interface \vec{k}_{\parallel} correspond to: (i) the leaky FP mode above the light line, and (ii) the confined GW mode below the light line. For a specific case of a SiC film with thickness d = 570 nm, the dispersion relations $\omega(\vec{k}_{\parallel}) \equiv \omega_r(\vec{k}_{\parallel}) +$ $i\omega_i(\vec{k}_{\parallel})$ for these modes are plotted in Fig. 2. Because the FP mode is leaky, it has a low quality factor $Q = \omega_r / \omega_i$. However, coupling to the GW mode requires a high-index prism or a diffraction grating, and its O is limited only by the material losses. As shown below, when the metal film is patterned, both FP and GW modes can hybridize with SSPs giving rise to highly confined modes whose spectral properties can be tuned by the size and shape of the perforations, and whose confinement drastically exceeds that of either the SSPs or the modes of the unperforated structure.



FIG. 2 (color online). Family of dispersion curves of the *p*-polarized eigenmodes of the heterostructure shown in Fig. 1 for different hole sizes: stars (a) unperforated metal; pluses (b) $L_X = L_Y = 1.2 \ \mu \text{m}$; circles (c) $L_X = L_Y = 1.8 \ \mu \text{m}$. $P = 3.84 \ \mu \text{m}$ and $d = 570 \ \text{nm}$. Color: the quality factor of the modes. Solid curve is the air light line.

Next, we consider a periodically perforated metal film as shown in Fig. 1. SSPs are introduced by generalizing Eq. (1) to include the effects of diffraction. Specifically, using the standard scattering matrix formulation, the reflection coefficient, which connects different diffractive orders, is expressed in the matrix form:

$$\hat{r}_{\text{slab}} = \hat{r}_{12} + \hat{t}_{21} \exp(i\hat{\delta})\hat{r}_{23}\hat{Z}\exp(i\hat{\delta})\hat{t}_{12}, \qquad (3)$$

where \hat{Z} is the multipass matrix given by $\hat{Z} = [\hat{I} - \exp(i\hat{\delta})\hat{r}_{21}\exp(i\hat{\delta})\hat{r}_{23}]^{-1}$. Complex eigenfrequencies of the hybrid SSPs correspond to the roots of the equation $Det[\hat{r}_{slab}^{-1}(\omega, \vec{k})] = 0$.

To make a further connection of hybrid SSPs to the modes of unperforated heterostructure, we introduce two effective complex quantities with tildes for a perforated film: $\tilde{r}_{23}\tilde{Z} \equiv (\hat{r}_{23}\hat{Z})_{00}$ and $\tilde{Z} \equiv 1/(1 - r_{21}\tilde{r}_{23}e^{2i\delta})$. By comparing Eq. (1) to Eq. (3) and by using the above definitions, we find that

$$\tilde{r}_{23} \equiv |\tilde{r}_{23}| e^{i\tilde{\phi}_{23}} = \frac{\sum}{1 + r_{21}e^{2i\delta}\sum},$$
(4)

where $\sum \equiv \sum_{\vec{G}} (\hat{r}_{23})_{0\vec{G}} (\hat{Z})_{\vec{G}0}$ involves summation over all the reciprocal lattice vectors \vec{G} . These definitions enable us to use the scalar Eqs. (1) and (2) by replacing transmission and reflection coefficients and the corresponding phases with their effective counterparts. For example, the modified resonant phase-matching condition is obtained by replacing $\phi_{23} = \pi$ in Eq. (2) with $\tilde{\phi}_{23}$, which can considerably deviate from π . As will be shown below, the size and shape of the hole can strongly influence $\tilde{\phi}_{23}$, thereby shifting the absorption peak from the Fabry-Pérot resonance $d = \lambda_{\rm FP}/4n(\lambda_{\rm FP})$.

We calculated the scattering matrices (\hat{r}_{23} and \hat{t}_{23}) using the semianalytic modal matching technique [19], and analytically continued it into the complex ω plane. The resulting dispersion curves for hybrid SSPs both above (leaky SSPs) and below (confined SSPs) the light line are plotted in Fig. 2, where j = (a, b, c) labels the hole size (see caption), and the color indicates the quality factor Q of the modes.

First we focus on dispersion curves below the light line: the guided mode of the unperforated structure GW (a), and the two hybrid SSPs [SSP-GW (b) and SSP-GW (c)] whose dispersion curves are controlled by the holes' size. As the hole size increases, the dispersion curves depart from the light line, thereby indicating high spatial confinement. Flattening of the dispersion curves for larger hole sizes also indicates an increasing density of states which can be utilized for plasmon-enhanced infrared emission [13]. Strong concentration of the magnetic field of the hybrid SSP-GW mode inside the hole [Fig. 3 inset (a)] explains the high sensitivity of this mode to the size and shape of the hole. Figure 3 illustrates that the confinement of the SSP-GWs exceeds that of both classes of waves (GWs and pure SSPs without the dielectric film) from which these hybrid SSPs originate. The figure shows



FIG. 3 (color online). Transverse distribution of electromagnetic energy density averaged over the unit cell for the case of (i) SSP-GW of perforated heterostructure, (ii) GW of unperforated heterostructure, and (iii) SSP of uncoated perforated PEC. Parameters are the same as in Fig. 2. Insets show the fields corresponding to the excitation of hybrid SSPs given in Fig. 2.

energy profiles of three modes at the particular subwavelength frequency, corresponding to the SSP-GW (c) mode at $k_X = \pi/P$ (i), a GW mode of the unperforated structure (ii), and a pure SSP of a thick perforated metal film surrounded by air (iii). Clearly, the hybrid SSPs have the highest confinement and the highest concentration of energy inside the dielectric film: 15% (70%) of the SSP-GW (GW) mode resides outside of the dielectric slab.

Hybridization between FP modes and SSPs produce leaky hybrid SSPs above the light line as shown in Fig. 2 by the progression from FP to SSP-FP modes. These hybrid leaky SSPs have a similar three-dimensional magnetic field profile to that of the guided SSP-GW modes as shown in the inset (a) to Fig. 3. Because fields are concentrated inside the perforation, spectral properties and the lifetime of the SSP-FP modes are strongly affected by the holes' size $L_{X,Y}$. Their transverse confinement also significantly exceeds that of FP modes as indicated by the Qfactor shown by color in Fig. 2. The SSP-FP mode lifetime Q/ω and field confinement both increase with $L_{X,Y}$. The corresponding energy density profiles are similar to those plotted for the confined modes in Fig. 3. Note that, in addition to the SSP-FP modes, there is another leaky hybrid SSP labeled SSP-GW (j) above the light line whose field distribution [shown in Fig. 3 inset (b)] is centered outside of the hole. Therefore, the spectral position of the leaky SSP-GW modes is not strongly affected by the holes' dimensions. Because SSP-FP and SSP-GW modes are leaky above the light line, they can be experimentally observed using conventional infrared spectroscopy as presented below.

Experimental results.—A SiC film of thickness d = 570 nm was heteroepitaxially grown on a Si(100) substrate wafer, and an air-bridged membrane with area $(500 \ \mu m)^2$ was produced after KOH back-etching of the Si substrate. A 100 nm Au film was thermally deposited on the newly exposed side of the SiC. Metal perforations were produced using a focused ion beam over a $(100 \ \mu m)^2$ area. Optical

characterization (reflection, transmission) was performed using a Thermo Scientific Continuum microscope coupled to a Nicolet 6700 FTIR Spectrometer. In all measurements, transmission was less than 10%. Therefore, we will focus on reflectivity $R(\lambda)$ and absorptivity $A(\lambda)$ spectra for the rest of this Letter. First, we measured $R(\lambda)$ prior to perforating the metal film which is shown by dot-dashed lines in Fig. 4. The broad reflection dip at $\lambda_{\rm FP} = 13.3 \ \mu m$ corresponds to coupling to FP mode.

Next, we measured $R(\lambda)$ and $A(\lambda)$ for the perforated metal structures and plotted them alongside the results of the finite-elements COMSOL simulations in Fig. 4. Two hole sizes were used as perforations: small square holes [Fig. 4(a)] and larger rectangular holes [Fig. 4(b) and 4(c)]. As predicted by the theory of hybrid SSPs, reflectivity curves reveal two reflection minima, which also correspond to absorption maxima. Thus, the metal perforation causes $R(\lambda)$ to drop to zero and absorption $A(\lambda)$ to reach nearly unity. The physical reason for this enhanced absorptivity is resonant coupling to leaky SSP-FP (long-wavelength peak) and SSP-GW (short-wavelength peak) modes.

Experimental results confirm that the spectral position of the SSP-GW dip ($\lambda = 13.25 \ \mu$ m) is almost independent of the size and shape of the holes, while that of SSP-FP dip is very sensitive to hole size and, for rectangular holes, is polarization sensitive. The SSP-FP absorption peak (e.g., at $\lambda = 14.20 \ \mu$ m for light polarized along the short dimension of the large rectangular hole) is especially remarkable because it occurs far from the FP resonance in the spectral region where SiC is not very absorptive: n = 4.6 + 0.04i. Without perforation, the round-trip absorptivity of the



FIG. 4 (color online). Reflection (blue [dark gray]) and absorption (red [medium gray]) curves obtained from experimental measurements (crosses) and finite-element simulations (solid lines) for different hole dimensions $L_X \times L_Y$ and incident light polarizations. (a) $L_X = L_Y = 1.2 \ \mu\text{m}$, polarization independent; (b) $L_X = 1.45 \ \mu\text{m}$, $L_Y = 1.75 \ \mu\text{m}$, y polarized; (c) $L_X = 1.45 \ \mu\text{m}$, $L_Y = 1.75 \ \mu\text{m}$, x polarized. Black dashdotted curves: reflection from unperforated Au film and SiC structure.



FIG. 5 (color online). (a) Reflection phase shift $\tilde{\phi}_{23}$ at the reflectivity minima for (i) rectangular holes as a function of L_X (crosses), and (ii) U-shaped holes as a function of t (circles). (b) Family of reflection spectra [different values of t] for the U-shaped holes.

 $d = \lambda/25$ SiC film is only $8\pi \operatorname{Im}(n)d/\lambda = 4\%$. This absorption enhancement is caused by the excitation of the high-Q SSP-FP mode which strongly traps and enhances the electromagnetic field inside the weakly absorbing film, turning it into a "perfect" absorber.

Another degree of freedom to confine electromagnetic energy is to use more sophisticated hole shapes that exhibit site (or shape) resonances [10,16]. For example, a strong confinement even in a thinner heterostructure can be accomplished by employing relatively simple (and feasible for fabrication) U-shaped holes [20] shown in Fig. 5(a). For instance, in the case of the SSP-FP resonance, use of U-shaped holes causes even more dramatic redshifting which facilitates trapping of electromagnetic fields by a subwavelength thick heterostructure. A family of reflectivity spectra shown in Fig. 5(b) correspond to U shapes with increasing metal "tongue" length t [see inset to Fig. 5(a)]. The figure indicates that, counterintuitively, the spectral position of the reflection dip redshifts even as the remaining hole area decreases with increasing t. This effect is due to the LC-like resonances of the U shape occurring for an electric field polarized parallel to the tongue [20]. This resonance manifests itself in the increased effective reflection phase ϕ_{23} . ϕ_{23} obtained for both rectangular and U-shaped holes at the respective reflectivity dips is shown by crosses and circles in Fig. 5(a) as a function of L_X and t, respectively. The U shape's parameter t has a more pronounced effect on $\tilde{\phi}_{23}$ (and, by extension, on the spectral position of the reflection dip) than the overall size L_X of the rectangular hole. In the latter case, the reflection phase $\tilde{\phi}_{23}$ saturates around the value of 1.25π , while in the case of the U-shaped holes, $\tilde{\phi}_{23}$ approaches $3\pi/2$, with high value of $d\tilde{\phi}_{23}/dt$ indicating strong sensitivity to the geometry of the U shape.

In conclusion, we have predicted and experimentally demonstrated that a heterostructure comprised of a periodically perforated metal film coated with a high-index dielectric layer supports strongly confined hybrid spoof surface plasmons. This extraordinary confinement is achieved through hybridization between two weakly confined sets of modes: SSPs supported by the perforated metal film and guided modes supported by the dielectric layer. Hybrid SSPs retain tunability due to strong sensitivity to the holes' size and shape. As an experimental proof of principle, we have demonstrated that hybrid SSPs can turn weakly absorbing ultrathin semiconductor films into spectrally tunable perfect absorbers. Hybrid SSPs may find practical applications in multispectral infrared imaging, thermophotovoltaics, on-chip light sources, and infrared detectors.

This work was supported by NSF Grants No. ECCS-0709323 and No. CMMI-0928664, and the AFOSR MURI Grants No. FA9550-06-1-0279 and No. FA9550-08-1-0394.

*gena@physics.utexas.edu

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